TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVXC3245FS

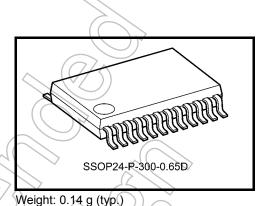
Dual Supply Octal Configurable Voltage Interface Bus Transceiver

The TC74LVXC3245FS is a dual supply, advanced high-speed CMOS octal configurable voltage interface bus transceiver fabricated with silicon gate CMOS technology.

Designed for use as an interface between a 3.3 V bus and a 3.3V to 5 V bus in mixed 3.3 V/5 V supply systems' it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is intended for 2 way asynchronous communication between data busses.

The direction of data transmission is determined by the level of the DIR input. The enable input (\overline{G}) can be used to disable the device so that the buses are effectively isolated. The A-port interfaces with



the 3.3-V bus, the B-port with the 3.3V to 5V bus. This device will allow the V_{CCB} voltage source pin and I/O pins on the B port to float when \overline{G} is "H".

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- Bi-directional interface between 3 V and 5 V buses
- High-speed: t_{pd} = 8.5 ns (max)
 - (V_{CCA} = 3.3 V, V_{CCB} = 5.0 V)
- Low power dissipation: I_{CC} = 8 μA (max) (Ta = 25°C)
- Symmetrical output impedance: I_{OUTA} = ±24 mA (min)

 $I_{OUTB} = \pm 24 \text{ mA} (\text{min})$

 $(V_{CCA} = V_{CCB} = 3.0 \text{ V})$

- Low noise: V_{OLP} = 1.5 V (max)
- Flexible V_{CCB} operating range

resistors.

- Allows B port and V_{CCB} to float simultaneously when G is "H'
- Package: SSOP (shrink small outline package)

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result. All floating (high impedance) bus pin must have their input levels fixed by means of pull-up or pull-down

(21)

B1

Pin Assignment (top view)

IEC Logic Symbol

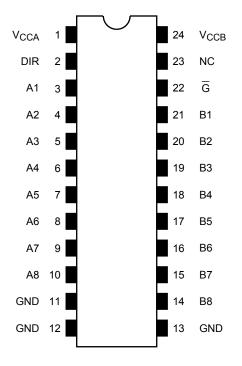
G (22) G3

(2)

(3)

DIR

A1 -



(20) (4) A2 -B2 A3 (5) (19) B3 (18) (6) A4 -B4 (17) (7) A5 B5 (16) (8) B6 A6 $\overline{\bigcirc}$ (15) (9) B7 A7 (10) (14) B8 A8

3 EN 1 (BA)

3 EN 2 (AB)

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 $(\triangleright$

 2∇

Truth Table

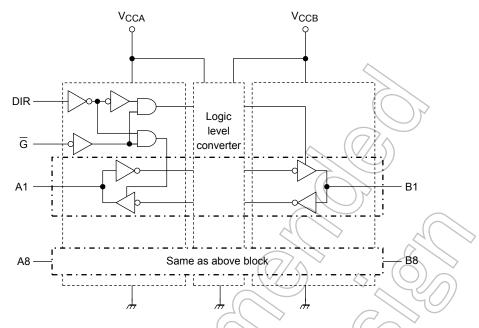
Inp	outs	Outputs	Eunction				
G	DIR	A-Bus		B-Bus			
L	L	A = B	Output	Input			
L	Н	B = A	Input	Output			
Н	Х	z	High impedance				

X: Don't care

Z: High impedance

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Block Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CCA}	-0.5 to 7.0	
(Note 2)	VCCB	-0.5 to 7.0))
DC input voltage (DIR, \overline{G})	VIN		V
DC bus I/O voltage	VITOA	–0.5 to V _{CCA} + 0.5	V
DC bus I/O voltage	V _{WOB}	–0.5 to V _{CCB} + 0.5	v
Input diode current	7 /ik	±20	mA
Output diode current	Лиок	±50	mA
DC output current		±50	mA
	IOUTB	±50	ША
DC V _{CC} /ground current	ICCA	±200	mA
	I _{CCB}	±200	ШA
Power dissipation	PD	180	mW
Storage temperature	Tstg	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Don't supply a voltage to V_{CCB} terminal when V_{CCA} is in the OFF state.

Operating Ranges (Note 1)

Characteristics		Symbol	Rating	Unit	
Supply voltage range		V _{CCA}	2.7 to 3.6	v	
	(Note 2)	V _{CCB}	3.0 to 5.5	v	
Input voltage	(DIR, \overline{G})	V _{IN}	0 to V _{CCA}	V	
Bus I/O voltage		V _{I/OA}	0 to V _{CCA}	v	\sim
Bus I/O voltage		V _{I/OB}	0 to V _{CCB}	Ň	
Operating temperature		T _{opr}	-40 to 85	°C	$\overline{\Omega}$
			0 to 8		$\bigvee \bigcirc$
Input rise and fall time		dt/dv	(V _{CCA} = 2.7 to 3.6 V)	ns/V	
		adav	0 to 8)7
			$(V_{CCB} = 3.0 \text{ to } 5.5 \text{ V})$		シ

Note1: The operating ranges are required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND. Please connect both bus inputs and the bus outputs with V_{CC} or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note2: Don't use in $V_{CCA} > V_{CCB}$.

Electrical Characteristics

DC Characteristics

Oherneteri		Sym-	Tast Osarl	4 ¹			-	Га = 25°С)	Ta –40 to	= 85°C	Unit
Characteri	SUCS	bol	Test Condi	uon	V _{CCA} (V)	V _{CCB} (V)	Min	Тур. 🗸	Max	Min	Max	Unit
	-				2.7	3.0	2.0	_	\geq	2.0	_	
	V_{IHA}	DIR, \overline{G} , An		3.0	3.6	2.0	_	Æ	2.0	_		
Input voltage	Т				3.6	5.5	2.0	10		2.0	_	V
(V _{CCA})	a				2.7	3.0	\frown	<u> </u>	0.8	—	0.8	v
	L-level	V_{ILA}	DIR, G, An		3.0	3.6	- 7		0.8	—	0.8	
					3.6	5.5	_()	0.8	—	0.8	
	ē				2.7	3.0	2.0	\rightarrow	_	2.0	_	
laavit	H-level	VIHB	Bn		3.0	3.6	2.0	<u> </u>		2.0	\rightarrow	
Input voltage	-				3.6	5.5	3.85			3.85	> -	V
(V _{CCB})	ē			2.7	3.0	H	$-\Diamond$	0.8	HA	0.8	, in the second s	
	L-level	VILB	Bn		3.0	3.6	_	_	0.8	L	0.8	
					3.6	5.5		((1.65	~_	1.65	
				I _{OH} = -100 μA	3.0	3.0	2.9	3.0	\mathbb{Z}	2.9	—	
		Voha		I _{OH} = -12 mA	3.0	3.0	2.56	\square) —	2.46		
	H-level			I _{OH} = -24 mA	3.0	3.0	2.35))-		2.25	_	
Outrust	_		V _{INA} = V _{IHA} or V _{ILA} V _{INB} = V _{IHB} or	I _{OH} =-12 mA	2.7	3.0	2.3	/_	_	2.2		
Output voltage (V _{CCA})				I _{OH} = −24 mA	2.7	4.5	2.1			2.0		V
(VCCA)			VILB	l _{OL} ≑ 100 μA	3.0	3.0	_	0	0.1	_	0.1	
	vel			1 _{OL} = 24 mA	3.0	3.0	_		0.36	_	0.44	
	L-level	Vola		I _{OL} = 12 mA	2.7	3.0	_	_	0.36	_	0.44	
		≤ 2	~	I _{OL} = 24 mA	2.7	4.5			0.42	—	0.5	

DC Characteristics (continued)

			Sym- Test Condition					Γa = 25°0	2	Ta = -40 to 85°C		Unit		
Characters	SUCS	bol			V _{CCA} (V)	V _{CCB} (V)	Min	Тур.	Max	Min	Max	Unit		
			I _{OH} = –100 μA	3.0	3.0	2.9	3.0	1/	2.9					
	H-level	V _{OHB}		I _{OH} = -12 mA	3.0	3.0	2.56			2.46				
Output	H-le	VOHB	V _{INA}	I _{OH} = -24 mA	3.0	3.0	2.35	10		2.25				
voltage (V _{CCB})			= V _{IHA} or V _{ILA} V _{INB}	I _{OH} = -24 mA	3.0	4.5	3.86		\bigcirc	3.76	_	V		
(VCCB)			$= V_{IHB}$ or V_{ILB}	I _{OL} = 100 μΑ	3.0	3.0	_((0	0.1	_	0.1			
	L-level	V _{OLB}		I _{OL} = 24 mA	3.0	3.0	ý.	\rightarrow	0.36	Æ	0.44			
				I _{OL} = 24 mA	3.0	4,5		- <	0.36		0.44			
0 -1-1		I _{OZA}	$V_{INA} = V_{IHA} \text{ or } V_{IL}$	$V_{INA} = V_{IHA}$ or V_{ILA}		3.6	Ŀ,		±0.5	14)) ±5.0			
3-state outp Off-state	but	OLN	$V_{INB} = V_{IHB}$ or V_{IL}		3.6	5.5			±0.5	50	±5.0	μA		
current		I _{OZB}	$VI/OA = V_{CCA}$ or C	3.6	3.6	—	_((±0.5		±5.0				
		02D	VI/OB = V _{CCB} or GND		3.6	5.5	_	\overline{a}	±0.5		±5.0			
Input leakag	ge	I _{IN}	V_{IN} (DIR, \overline{G}) = V _{CCA} or GND	~	3.6	3.6 5.5		X	±0.1 ±0.1		±1.0 ±1.0	μA		
		ICCT	PER INPUT: V _{IN} = 3.0 V			3.6))	0.35		0.5	mA		
Quiescent supply current		I _{CCA1}	$An = V_{CCA} \text{ or GNI}$ $Bn = Open,$ $\overline{G} = V_{CCA}$ $DIR = V_{CCA},$ $V_{CCB} = Open$	3.6	Open	>-	_	5		50	μΑ			
		VINA = VIHA or VIL	A	3.6	3.6		_	5		50]			
		I _{CCA2}	$V_{INB} = V_{IHB}$ or V_{IL}	В	3.6	5.5			5		50			
		-ICCB	$V_{INA} = V_{IHA}$ or V_{IL}	A	3.6	3.6	_	_	5		50			
		-COB	$V_{INB} = V_{IHB}$ or V_{IL}	B	3.6	5.5	—	—	8	—	80			

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$, $V_{CCA}=2.7 \text{ to } 3.6 \text{ V}$)

Characteristics	Symbol Test Condition _F			Ta = 25°C			Ta –40 to 8	Unit	
Characteristics	Cymbol			Min	Тур.	Max	Min	Max	Onit
Propagation delay time	t _{pLH}		5.0 ± 0.5	—	5.7	8.0	1.0	8.5	ns
$(An \rightarrow Bn)$	t _{pHL}	Innut: An	3.3 ± 0.3	_	6.2	8.5	1.0	9.0	115
3-state output enable time	t _{pZL}	Input: An Output: Bn	5.0 ± 0.5	_	6.5	9.5	1.0	10.0	ns
$(\overline{G} \rightarrow Bn)$	t _{pZH}	(DIR = "H")	3.3 ± 0.3	—	7.4	10.5	1.0	11.5	115
3-state output disable time	t _{pLZ}		5.0 ± 0.5		7.3	9.5	1.0	10.0	20
$(\overline{G} \rightarrow Bn)$	t _{pHZ}		3.3 ± 0.3	$ \rightarrow $	6.6	9.5	1.0	10.0	ns
Propagation delay time	t _{pLH}		5.0 ± 0.5	_((4.6	7.5	1.0	8.0	ns
$(Bn \rightarrow An)$	t _{pHL}	Januti Da	3.3 ± 0.3		5.2	7.5	1.0	8.0	115
3-state output enable time	t _{pZL}	Input: Bn Output: An	5.0 ± 0.5	467	7.0	10.5	1.0	11.5	ns
$(\overline{G} \rightarrow An)$	t _{pZH}	(DIR = "L")	3.3 ± 0.3	\leq	7.0	10.5	2 1.0	11.5	
3-state output disable time	t _{pLZ}		5.0 ± 0.5	$\langle \gamma \rangle$	6.1	9.5)1.0	10.0	20
$(\overline{G} \rightarrow An)$	t _{pHZ}		3.3 ± 0.3	92	6.0	9.5	(1,0)	10.0	ns
Output to output skew	t _{osLH}	(Note 1)	5.0 ± 0.5	> —	-6	71.5	\searrow	1.5	20
	t _{osHL}		3.3 ± 0.3	_	-C	1.5)	—	1.5	ns
Input capacitance	C _{INA}	dir, g	5.0 ± 0.5		5	10	—	10	pF
Bus input capacitance	C _{I/O}	An, Bn	5.0 ± 0.3		8) —	_	_	ы
Power dissipation capacitance	Capit	$A \rightarrow B (DIR = "H")$	50+05		4		_		
	C _{PDA}	$B \rightarrow A (DIR = L")$	5.0 ± 0.5		38		_	_	pF
(Note 2)		$A \rightarrow B (DIR = "H")$	50 ± 05	\searrow	88	_		_	μг
	C _{PDB}	$B \rightarrow A(DIR = "L")$	5.0 ± 0.5	_	7	_	_	_	

Note 1: Parameter guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

ICC (opr) = CPD · VCC · fIN + ICC / 8 (per bit)

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

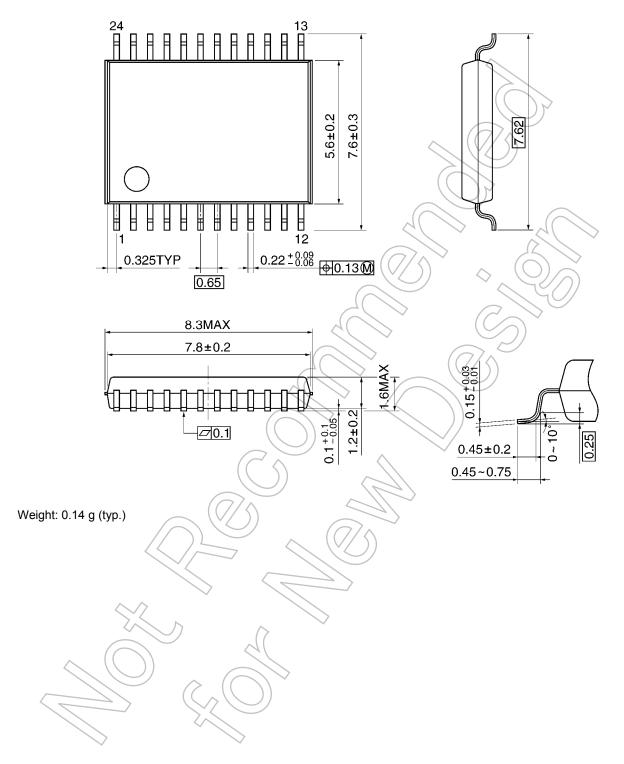
Characteristics		Symbol	Test Condition	V _{CCA} (V)	V _{CCB} (V)	Тур.	Limit	Unit
Quiet output maximum	V _{OL} (A)	V _{OLPA}	Input: Bn	3.3	3.3	_	0.9	
dynamic	VOL (//)	VOLPA	Output: An	3.3	5.0		0.9	
Quiet output mimimum)/a. (A)	Vanue	(DIR = "L")	3.3	3.3	_	-0.9	
dynamic	V _{OL} (A)	V _{OLVA}		3.3	5.0)/	-0.9	v
Quiet output maximum		M		3.3	3.3	-	0.8	v
dynamic	V _{OL} (B)	V _{OLPB}	Input: An Output: Bn	3.3	5.0		1.5	
Quiet output mimimum)/(D)	Manaa	(DIR = "H")	3.3	3.3		-0.8	
dynamic	V _{OL} (B)	V _{OLVB}		3.3	5.0		-1.2	
Minimum high level dynamic	V (A)		Input: An	3.3	3.3		2.0	V
input voltage	V _{IH} (A)	VIHDA	Input. An	3.3	5.0	\sum	2.0	v
Maximum low level dynamic	V _{IL} (A)	VILDA	Input: An	3.3	3.3	$\langle - \rangle$	0.8	V
input Voltage	VIL (A)	VILDA		3.3	5.0	14	0.8	v
Minimum high level dynamic	V _{IH} (B)	VIHDB	Input: Bn	3.3	3.3	2.0		V
input voltage	VIH (D)	VIHDB		3.3	(5.0)	3.5	_	v
Maximum low level dynamic	V _{IL} (B)	VILDB	Input:/Bn	3.3	3.3	0.8		v
input voltage	VIL (D)	▼ ILDB		3.3	5.0	1.5		v

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Package Dimensions

SSOP24-P-300-0.65D

Unit: mm



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